

Prof. Dr. Doris Schmitt-Landsiedel

Member of the Infineon Technologies
Supervisory Board since 2005



Person

Date of birth: December 13, 1952
Nationality: German

Education

1984 Dr. rer. nat., Technical University of Munich (TUM)
1980 Degree (Diplom) in Physics, Albert-Ludwigs-University Freiburg
1977 Degree (Diplom) in Electrical Engineering,
University Fridericiana Karlsruhe (TH)
1971 – 1980 Studies in Electrical Engineering and Physics,
Universities of Karlsruhe und Freiburg

Professional career

Since 1996 Professor and head of chair, Institute for Technical Electronics,
Department of Electrical, Electronic and Computer Engineering,
Technical University of Munich (TUM)
1983 – 1996 Various (management) positions, R&D department,
Siemens AG (Munich)
Research on high speed analog and digital CMOS and BICMOS ci-
cuits, ultralow power CMOS circuits for digital hearing aids, static, dy-
namic and nonvolatile memory, yield monitoring of CMOS processes
1981 – 1983 Doctoral Scholarship, Central R&D, Siemens AG (Munich)

Other memberships and mandates (selection)

2008 - 2014 Member of the Senate of the German Research Foundation
2004 – 2010 Member of the German Scientific Council (Wissenschaftsrat)
2001 – 2007 Spokesperson of Collaborative Research Group “Selected Materials,
Processes and Devices for Ultra-large-scale Integrated Circuits” ,
German Research Foundation (DFG)